

Please type a plus sign (+) inside this box → +

PTO/SB/08B (08-00)

Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number

Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Complete if Known	
		Application Number	
		Filing Date	8/30/01
		First Named Inventor	Iwasaki, Tomio
		Group Art Unit	2823
		Examiner Name	FOURSON
		Attorney Docket Number	16869S-033100US
Sheet	2	of	2

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
G	001	KOJI MATSUO, <i>et al.</i> , "Reliable High-k TiO ₂ Gate Insulator Formed by Ultrathin TiN Deposition and Low Temperature Oxidation," 1999 <i>International Conference on Solid State Devices and Materials</i> , pp. 164-5.	
G	002	BENITO deCELIS, <i>et al.</i> , "Molecular Dynamics Simulation of Crack Tip Processes in Alpha-iron and Copper," <i>J. Appl. Phys.</i> (September 1983), 54(9):4864-78.	
G	003	THOMAS KWOK, <i>et al.</i> , "Molecular-dynamics Studies of Grain-boundary Diffusion," <i>Physical Review B</i> (15 May 1984), 29:5363-71.	
G	004	S.A. CAMPBELL, <i>et al.</i> , "Titanium Dioxide (TiO ₂)-based Gate Insulators," <i>IBM J. Res. Develop.</i> (May 1999), 43(3):383-91.	

Examiner Signature	FOURSON	Date Considered	8/20/03
-----------------------	---------	--------------------	---------

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.
PA 3167286 v1

